

74ABT125 Quad Buffer with 3-STATE Outputs

General Description

The ABT125 contains four independent non-inverting buffers with 3-STATE outputs.

Features

- Non-inverting buffers
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed latching protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability
- Disable time less than enable time to avoid bus contention

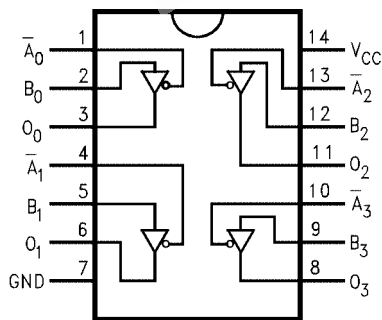
Ordering Code:

Order Number	Package Number	Package Description
74ABT125CSC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74ABT125CSJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT125CMT	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ABT125CMTCX_NL (Note 1)	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.
Pb-Free package per JEDEC J-STD-020B.

Note 1: "_NL" indicates Pb-Free package (per JEDEC J-STD-020B). Device available in Tape and Reel only.

Connection Diagram



Pin Descriptions

Pin Names	Descriptions
\bar{A}_n, B_n	Inputs
O_n	Outputs

Function Table

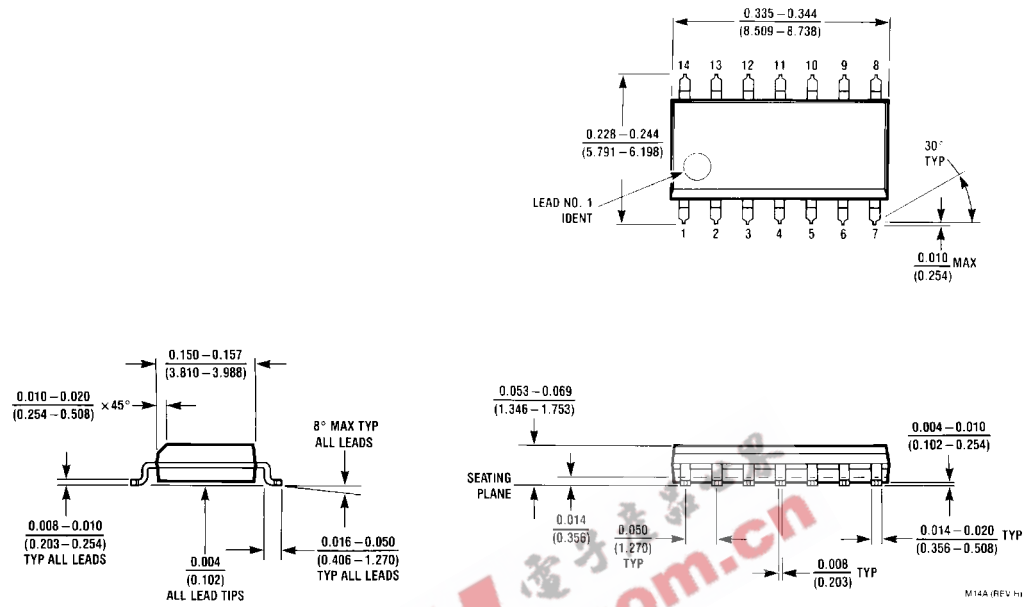
Inputs		Output
A_n	B_n	O_n
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
Z = HIGH Impedance
X = Immaterial

Absolute Maximum Ratings (Note 2)		Recommended Operating Conditions					
Storage Temperature	-65°C to +150°C	Free Air Ambient Temperature	-40°C to +85°C				
Ambient Temperature under Bias	-55°C to +125°C	Supply Voltage	+4.5V to +5.5V				
Junction Temperature under Bias	-55°C to +150°C	Minimum Input Edge Rate ($\Delta V/\Delta t$)					
V_{CC} Pin Potential to Ground Pin	-0.5V to +7.0V	Data Input	50 mV/ns				
Input Voltage (Note 3)	-0.5V to +7.0V	Enable Input	20 mV/ns				
Input Current (Note 3)	-30 mA to +5.0 mA						
Voltage Applied to Any Output in the Disabled or Power-Off State	-0.5V to 5.5V						
in the HIGH State	-0.5V to V_{CC}						
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)						
DC Latchup Source Current (Across Comm Operating Range)	-300 mA						
Over Voltage Latchup (I/O)	10V						
<p>Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.</p> <p>Note 3: Either voltage limit or current limit is sufficient to protect inputs.</p>							
DC Electrical Characteristics							
Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage				V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			-1.2	V	Min	$I_{IN} = -18$ mA
V_{OH}	Output HIGH Voltage	2.5			V	Min	$I_{OH} = -3$ mA
		2.0			V	Min	$I_{OH} = -32$ mA
V_{OL}	Output LOW Voltage			0.55	V	Min	$I_{OL} = 64$ mA
I_{IH}	Input HIGH Current			1	μ A	Max	$V_{IN} = 2.7$ V (Note 4)
				1	μ A	Max	$V_{IN} = V_{CC}$
I_{BVI}	Input HIGH Current Breakdown Test			7	μ A	Max	$V_{IN} = 7.0$ V
I_{IL}	Input LOW Current			-1	μ A	Max	$V_{IN} = 0.5$ V (Note 4)
				-1	μ A	Max	$V_{IN} = 0.0$ V
I_{ID}	Input Leakage Test				V	0.0	$I_{ID} = 1.9$ μ A, All Other Pin Grounded
I_{OZH}	Output Leakage Current			10	μ A	0-5.5V	$V_{OUT} = 2.7$ V; $\overline{OE}_n = 2.0$ V
I_{OZL}	Output Leakage Current			-10	μ A	0-5.5V	$V_{OUT} = 0.5$ V; $\overline{OE}_n = 2.0$ V
I_{OS}	Output Short-Circuit Current			-275	mA	Max	$V_{OUT} = 0.0$ V
I_{CEX}	Output HIGH Leakage Current			50	μ A	Max	$V_{OUT} = V_{CC}$
I_{ZZ}	Bus Drainage Test			100	μ A	0.0	$V_{OUT} = 5.5$ V; All Others GND
I_{CCH}	Power Supply Current			50	μ A	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			15	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current			50	μ A	Max	$\overline{OE}_n = V_{CC}$; All Others at V_{CC} or Ground
I_{CCT}	Additional I_{CC} /Input	Outputs Enabled		1.5	mA	Max	$V_i = V_{CC} - 2.1$ V
		Outputs 3-STATE		1.5	mA	Max	Enable Input $V_i = V_{CC} - 2.1$ V
		Outputs 3-STATE		50	μ A	Max	Data Input $V_i = V_{CC} - 2.1$ V
						Max	All Others at V_{CC} or Ground
I_{CCD}	Dynamic I_{CC} (Note 4)	No Load		0.1	mA/ MHz	Max	Outputs Open $\overline{OE}_n = GND$, (Note 5) One Bit Toggling, 50% Duty Cycle
<p>Note 4: Guaranteed, but not tested.</p> <p>Note 5: For 8 bits toggling, $I_{CCD} < 0.8$ mA/MHz.</p>							

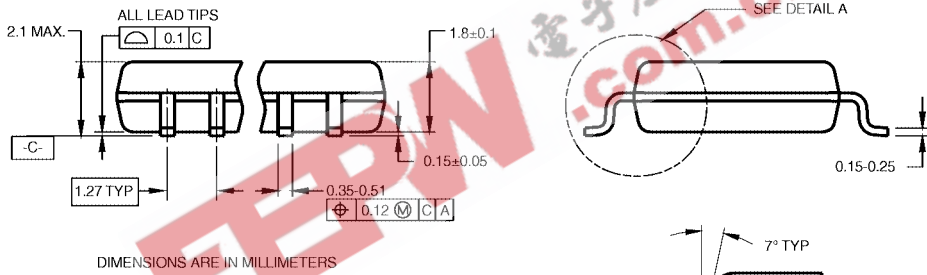
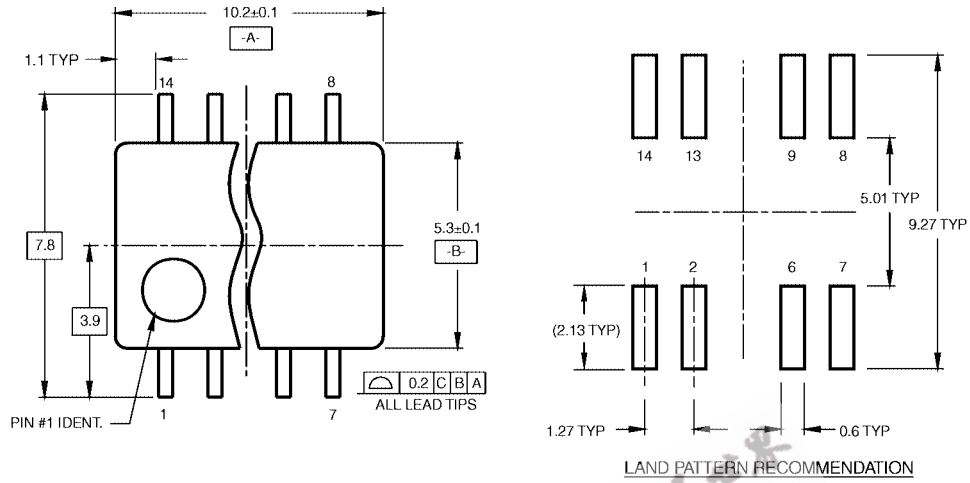
AC Electrical Characteristics							
Symbol	Parameter	T _A = +25°C V _{CC} = +5V C _L = 50 pF		T _A = -40°C to +85°C V _{CC} = 4.5V–5.5V C _L = 50 pF		Units	
		Min	Typ	Max	Min		Max
t _{PLH}	Propagation Delay	1.0		4.6	1.0	4.6	ns
t _{PHL}	Data to Outputs	1.0		4.9	1.0	4.9	
t _{PZH}	Output Enable	1.0		5.1	1.0	5.1	ns
t _{PZL}	Time	1.0		6.8	1.0	6.8	
t _{PHZ}	Output Disable	1.0		6.2	1.0	6.2	ns
t _{PLZ}	Time	1.0		5.5	1.0	5.5	
Capacitance							
Symbol	Parameter	Typ	Units	Conditions T _A = 25°C			
C _{IN}	Input Capacitance	5.0	pF	V _{CC} = 0V			
C _{OUT} (Note 6)	Output Capacitance	9.0	pF	V _{CC} = 5.0V			
<p>Note 6: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.</p>							

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

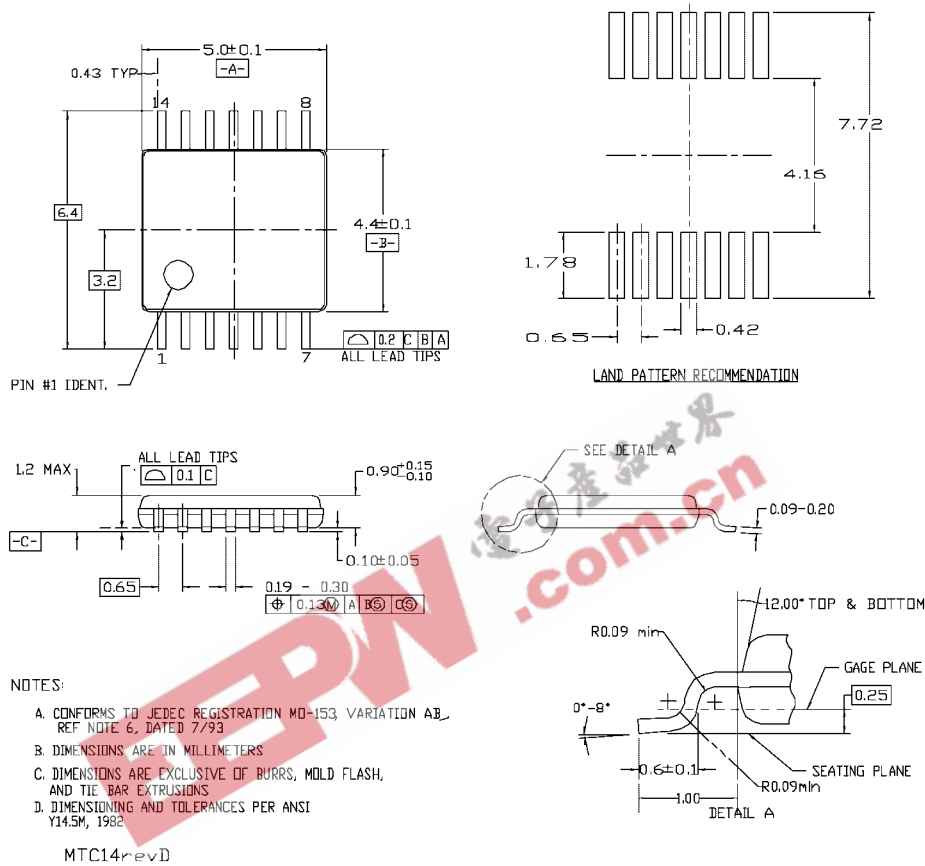


- NOTES:
- A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.
 - B. DIMENSIONS ARE IN MILLIMETERS.
 - C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

**Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D**

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC14

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